

KPFA-3010SURKCGKSYKC 3.0 x 1.0 mm Right Angle SMD Chip LED Lamp

DESCRIPTIONS

- The Hyper Red source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- The Green source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- The Super Bright Yellow device is made with AlGaInP (on GaAs substrate) light emitting diode chip
- Electrostatic discharge and power surge could damage the LEDs
- It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- All devices, equipments and machineries must be electrically grounded

FEATURES

- 3.0 x 1.5 x 1.0 mm right angle SMD LED, 1.0 mm thickness
- Low power consumption
- Wide viewing angle
- Ideal for backlight and indicator
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- Halogen-free
- Tinned pads for improved solderability
- RoHS compliant

APPLICATIONS

- Backlight
- Status indicator
- Home and smart appliances
- Wearable and portable devices
- Healthcare applications

ATTENTION

Observe precautions for handling electrostatic discharge sensitive devices

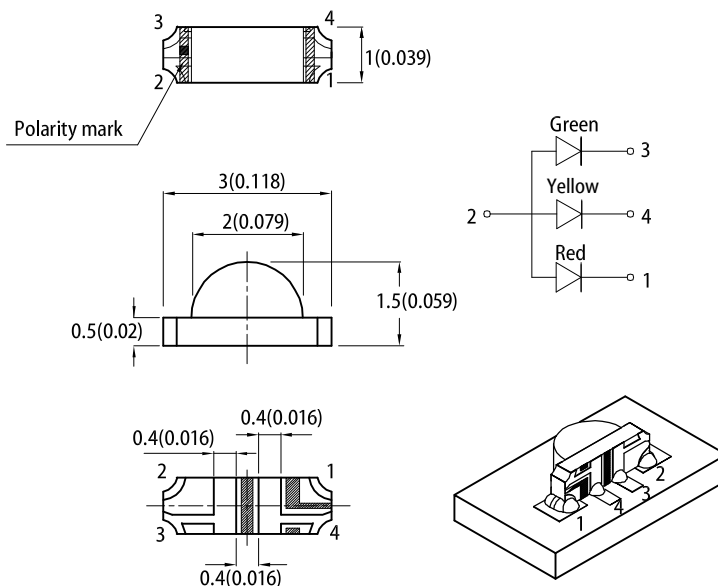


SELECTION GUIDE

Part Number	Emitting Color (Material)	Lens Type	Iv (mcd) @ 20mA ^[2]		Viewing Angle ^[1]
			Min.	Typ.	2θ1/2
KPFA-3010SURKCGKSYKC	■ Hyper Red (AlGaInP)	Water Clear	120	220	150°
	■ Green (AlGaInP)		*55	*80	
	■ Super Bright Yellow (AlGaInP)		20	45	
			*20	*45	
			120	180	
			*120	*180	

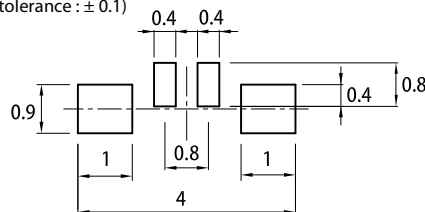
Notes:
 1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
 2. Luminous intensity / luminous flux: +/-15%.
 * Luminous intensity value is traceable to CIE127-2007 standards.

PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : ± 0.1)



Notes:
 1. All dimensions are in millimeters (inches).
 2. Tolerance is ±0.2(0.008") unless otherwise noted.
 3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
 4. The device has a single mounting surface. The device must be mounted according to the specifications.

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Symbol	Emitting Color	Value		Unit
			Typ.	Max.	
Wavelength at Peak Emission I _F = 20mA	λ _{peak}	Hyper Red Green Super Bright Yellow	645 574 590	-	nm
Dominant Wavelength I _F = 20mA	λ _{dom} ^[1]	Hyper Red Green Super Bright Yellow	630 570 590	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 20mA	Δλ	Hyper Red Green Super Bright Yellow	28 20 20	-	nm
Capacitance	C	Hyper Red Green Super Bright Yellow	35 15 20	-	pF
Forward Voltage I _F = 20mA	V _F ^[2]	Hyper Red Green Super Bright Yellow	1.95 2.1 2	2.5 2.5 2.5	V
Reverse Current (V _R = 5V)	I _R	Hyper Red Green Super Bright Yellow	-	10 10 10	μA
Temperature Coefficient of λ _{peak} I _F = 20mA, -10°C ≤ T ≤ 85°C	TC _{λpeak}	Hyper Red Green Super Bright Yellow	0.14 0.12 0.12	-	nm/°C
Temperature Coefficient of λ _{dom} I _F = 20mA, -10°C ≤ T ≤ 85°C	TC _{λdom}	Hyper Red Green Super Bright Yellow	0.05 0.08 0.07	-	nm/°C
Temperature Coefficient of V _F I _F = 20mA, -10°C ≤ T ≤ 85°C	TC _V	Hyper Red Green Super Bright Yellow	-1.9 -1.9 -1.9	-	mV/°C

Notes:

1. The dominant wavelength (λ_d) above is the setup value of the sorting machine. (Tolerance λ_d: ±1nm.)
2. Forward voltage: ±0.1V.
3. Wavelength value is traceable to CIE127-2007 standards.
4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

ABSOLUTE MAXIMUM RATINGS at T_A=25°C

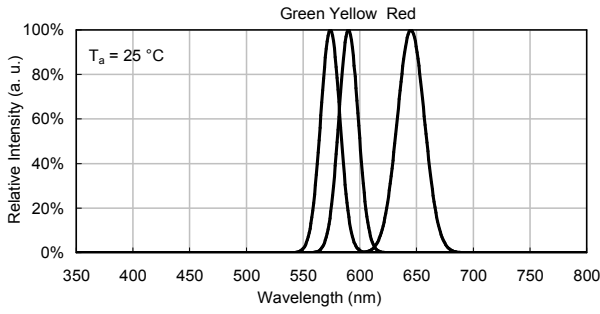
Parameter	Symbol	Value			Unit
		Hyper Red	Green	Super Bright Yellow	
Power Dissipation	P _D	75	75	75	mW
Reverse Voltage	V _R	5	5	5	V
Junction Temperature	T _j	115	115	115	°C
Operating Temperature	T _{op}	-40 to +85			°C
Storage Temperature	T _{stg}	-40 to +85			°C
DC Forward Current	I _F	30	30	30	mA
Peak Forward Current	I _{FM} ^[1]	185	150	175	mA
Electrostatic Discharge Threshold (HBM)	-	3000	3000	3000	V
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[2]	610	710	790	°C/W
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	500	600	680	°C/W

Notes:

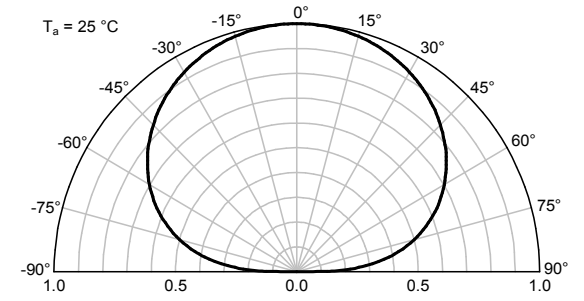
1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. R_{th JA}, R_{th JS} Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad).
3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

TECHNICAL DATA

RELATIVE INTENSITY vs. WAVELENGTH

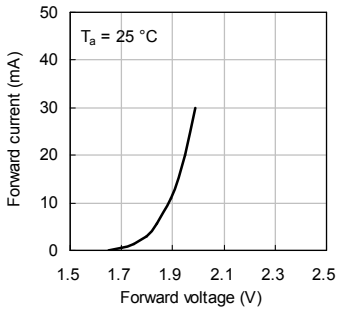


SPATIAL DISTRIBUTION

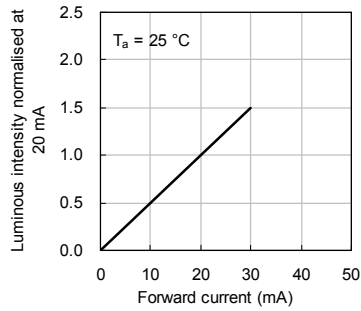


HYPER RED

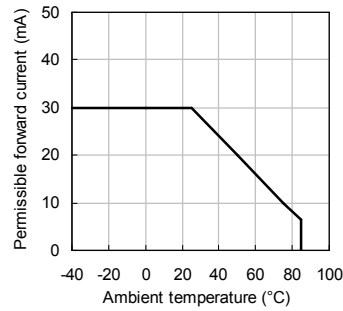
Forward Current vs. Forward Voltage



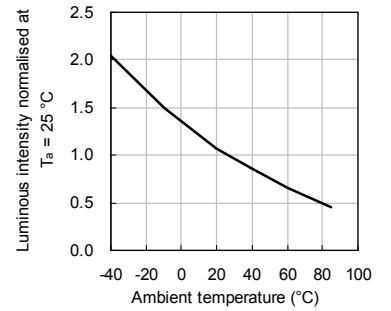
Luminous Intensity vs. Forward Current



Forward Current Derating Curve

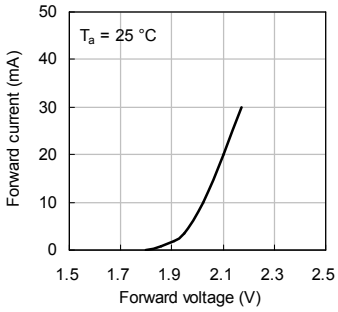


Luminous Intensity vs. Ambient Temperature

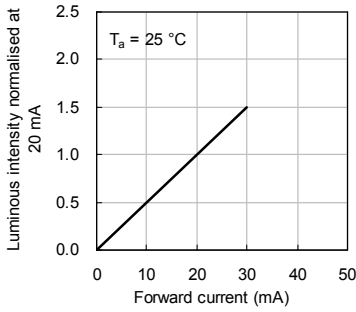


GREEN

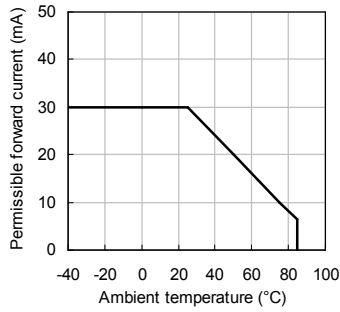
Forward Current vs. Forward Voltage



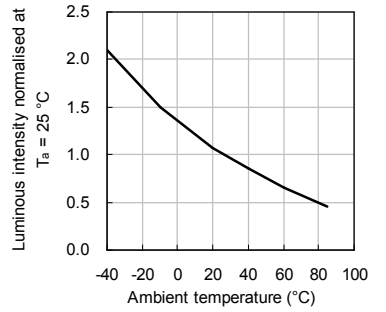
Luminous Intensity vs. Forward Current



Forward Current Derating Curve

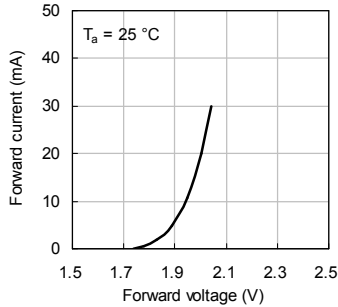


Luminous Intensity vs. Ambient Temperature

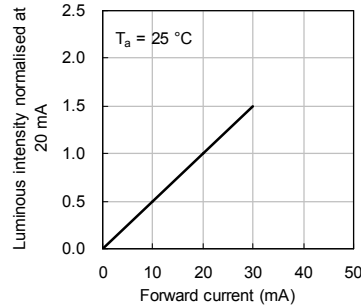


SUPER BRIGHT YELLOW

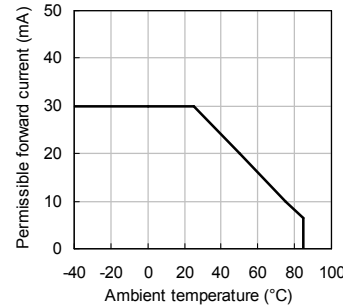
Forward Current vs. Forward Voltage



Luminous Intensity vs. Forward Current



Forward Current Derating Curve



Luminous Intensity vs. Ambient Temperature

